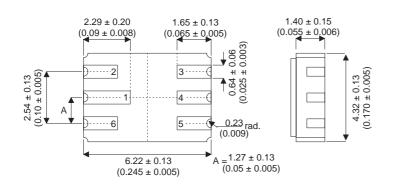




DUAL HIGH SPEED, MEDIUM POWER, NPN SWITCHING TRANSISTOR IN A HERMETICALLY SEALED CERAMIC SURFACE MOUNT PACKAGE

MECHANICAL DATA

Dimensions in mm (inches)



FEATURES

- DUAL SILICON PLANAR EPITAXIAL DUAL NPN TRANSISTOR
- HERMETIC CERAMIC SURFACE MOUNT PACKAGE
- SCREENING OPTIONS AVAILABLE

LCC2 PACKAGE Underside View

PAD 1 – Collector 1 PAD 4 – Collector 2 PAD 2 – Base 1 PAD 5 – Emitter 2 PAD 3 – Base 2 PAD 6 – Emitter 1

APPLICATIONS:

Hermetically sealed dual surface mount dual version of the popular 2N2369A for high reliability / space applications requiring small size and low weight devices.

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise stated)			PER SIDE	TOTAL DEVICE	
V_{CBO}	Collector – Base Voltage		40V	_	
V_{CEO}	Collector – Emitter Voltag	je	15V		
V_{EBO}	Emitter – Base Voltage		4.5V		
$I_{\mathbb{C}}$	Collector Current		200mA		
P_{D}	Total Device Dissipation	@ T _A =25°C	360mW	500mW	
		Derate above 25°C	2.06mW / °C	2.85mW / °C	
P_{D}	Total Device Dissipation	@ T _C =25°C	680mW/°C	800mW/°C	
		Derate above 25°C	3.88mW/°C	4.57mW/°C	
T_{STG} , T_{J}	Operating and Storage Temperature Range		−65 to +200°C		

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

Website: http://www.semelab.co.uk

E-mail: sales@semelab.co.uk

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

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2N2369ADCSM

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
V _{(BR)CEO*}	Collector – Emitter Breakdown Voltage	$I_C = 10mA$	I _B =0	15			V
V _{(BR)CBO}	Collector – Base Breakdown Voltage	$I_C = 10\mu A$	I _E =0	40			V
V _{(BR)EBO}	Emitter – Base Breakdown Voltage	I _E = 10μΑ	I _C =0	4.5			V
I _{CES}	Collector – Emitter Cut-off Current	V _{CE} = 20V	$V_{BE} = 0$			0.40	μА
I _{CBO}	Collector – Base Cut-off Current	V _{CB} = 20V	T _A = +150°C			30	
V _{CE(sat)*}	Collector – Emitter Saturation Voltage	I _C = 10mA	I _B = 1mA			0.20	-
			$T_A = +125^{\circ}C$			0.30	
		$I_C = 30 \text{mA}$	$I_B = 3mA$			0.25	V
		I _C = 100mA	I _B = 10mA			0.50]
V _{BE(sat)*}	Base – Emitter Saturation Voltage	$I_C = 10mA$	T _A = +25°C	0.70		0.85	V
		$I_B = 1mA$	$T_A = +125^{\circ}C$	0.59			
			$T_A = -55$ °C			1.02	
		$I_C = 30mA$	$I_B = 3mA$			1.15	1
		I _C = 100mA	$I_B = 10mA$			1.60	
h _{FE*}		$I_C = 10mA$	$V_{CE} = 0.35V$	40			
			$T_A = -55$ °C	20			
	Current Gain	$I_C = 30 \text{mA}$	$V_{CE} = 0.4V$	30			1 —
		$I_C = 10mA$	V _{CE} = 1.0V			120	
		I _C = 100mA	V _{CE} = 1V	20			
f _T	Transition Frequency	$I_C = 10mA$	$V_{CE} = 10V$	500			NALI-
		f = 100MHz		500			MHz
C _{ob}	Output Capacitance	$V_{CB} = 5V$	I _E = 0		4	pF	
		f = 140kHz					
t _s	Storage Time	$I_C = 10mA$	= 10mA			13	
		$I_{B1} = I_{B2} = 10 \text{mA}$]
t _{on}	Turn-On Time	I _C = 10mA	$V_{CC} = 3V$			12	ns
t _{off}	Turn-Off Time	I _{B1} = 3mA	$I_{B2} = 1.5 \text{mA}$			18	

^{*} Pulse Test: $t_p \leq 300 \mu s, \, \delta \leq 2\%.$

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